

## Features

- Glass passivated superfast recovery rectifiers
- Low leakage current
- Moisture sensitivity: level 1, per J-STD-020
- Solder dip 260°C, 10s
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Halogen-free according to IEC 61249-2-21 definition



Package: DO-214AB (SMC)

## Applications

For use in secondary rectification and freewheeling for ultrafast switching speeds of converters.

## Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	ES5A	ES5B	ES5C	ES5D	ES5F	ES5G	ES5J	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	300	400	600	V
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	210	280	420	V
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	300	400	600	V
Maximum average forward rectified current	$I_{F(AV)}$				5.0				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$				150				A
Rating for fusing( $t < 8.3\text{ms}$ )	$I^2t$				93.8				$\text{A}^2\text{sec}$
Operating junction and storage temperature range	$T_J, T_{STG}$				-55 to +150				$^\circ\text{C}$

## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Test Conditions	Symbol	ES5A	ES5B	ES5C	ES5D	ES5F	ES5G	ES5J	Unit		
Maximum instantaneous forward voltage	$I_F=5.0\text{A}, T_a=25^\circ\text{C}$	$V_F$	0.95				1.4		1.7	V		
	$I_F=5.0\text{A}, T_a=125^\circ\text{C}$		0.75				1.05		1.25			
Maximum DC reverse current at rated DC blocking voltage	$T_a=25^\circ\text{C}$	$I_R$	5.0							$\mu\text{A}$		
	$T_a=125^\circ\text{C}$		100									
Maximum reverse recovery time	$I_F=0.5\text{A}, I_R=1.0\text{A}, I_{RR}=0.25\text{A}$	$t_{rr}$	35							nS		
Typical junction capacitance	4.0V, 1MHz	$C_J$	95.3				100.4		52.6	pF		

## Thermal Characteristics

Parameter	Symbol	ES5A	ES5B	ES5C	ES5D	ES5F	ES5G	ES5J	Unit
Typical thermal resistance	$R_{\theta JA}^1$	27							$^\circ\text{C/W}$
	$R_{\theta JC}^1$	8							
	$R_{\theta JL}^1$	4							
	$R_{\theta CJ}^2$	5							

Notes:1. The thermal resistance from junction to ambient, case or mount, mounted on P.C.B with 30×30mm copper pads, 2 OZ, FR4 PCB

2. The thermal resistance from junction to case, mounted on P.C.B with 30×30mm copper pads, 2 OZ, Aluminum substrate PCB

## Ratings and Characteristics Curves ( $T_A=25^\circ\text{C}$ unless otherwise noted)

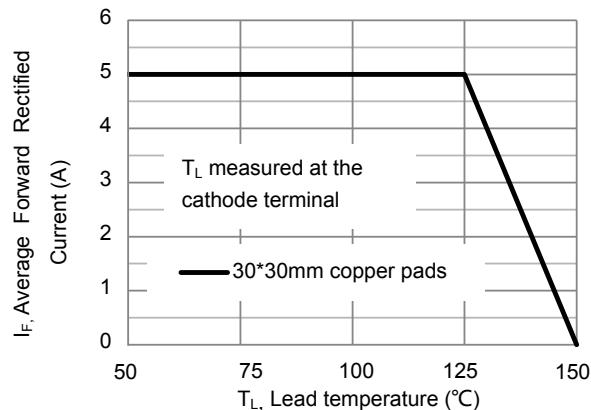


Figure 1. Forward Current Derating Curve

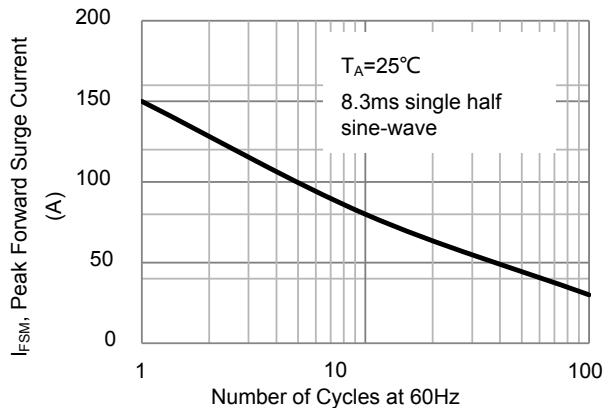


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

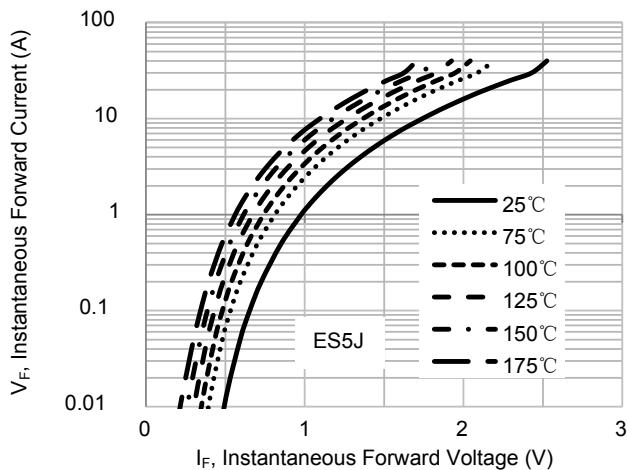


Figure 3. Typical Instantaneous Forward Characteristics

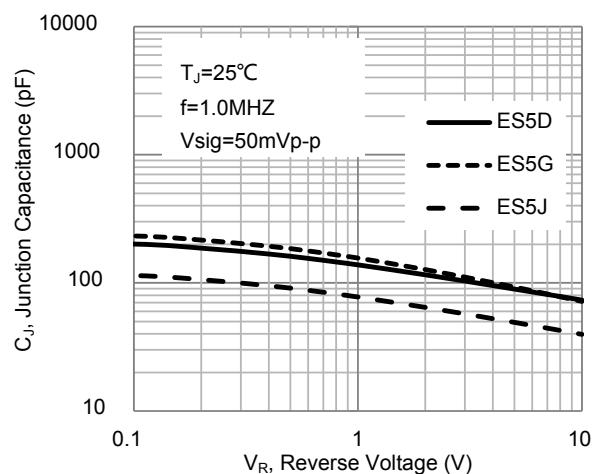


Figure 4. Typical Junction Capacitance

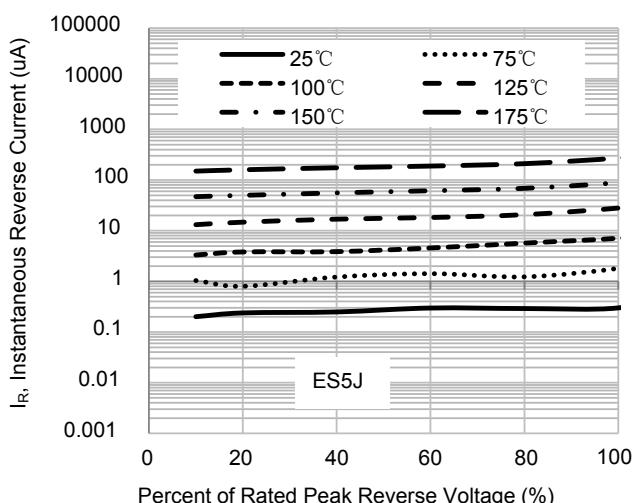


Figure 5. Typical Reverse Characteristics

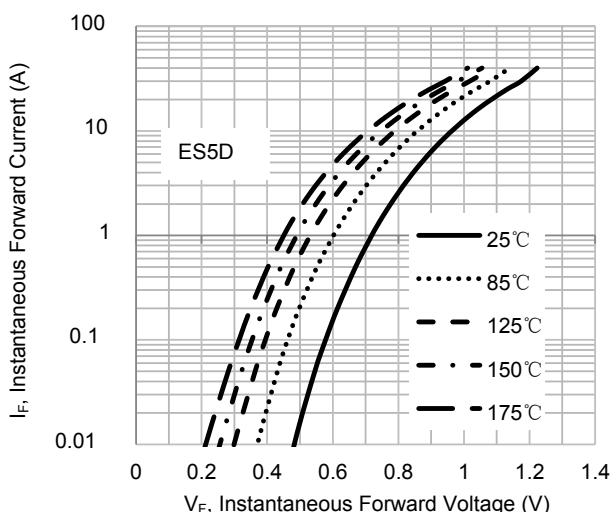
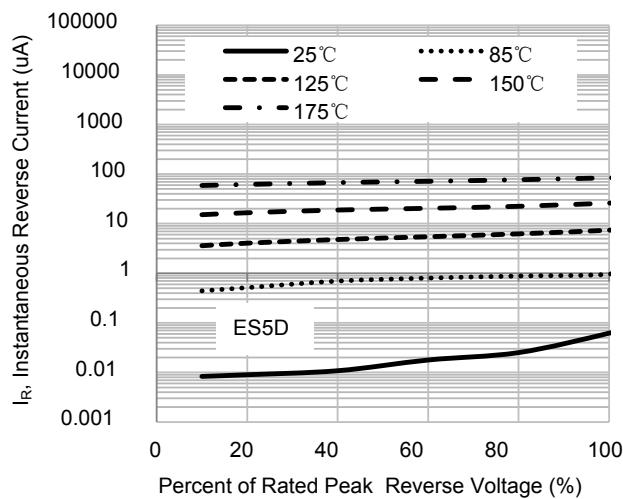
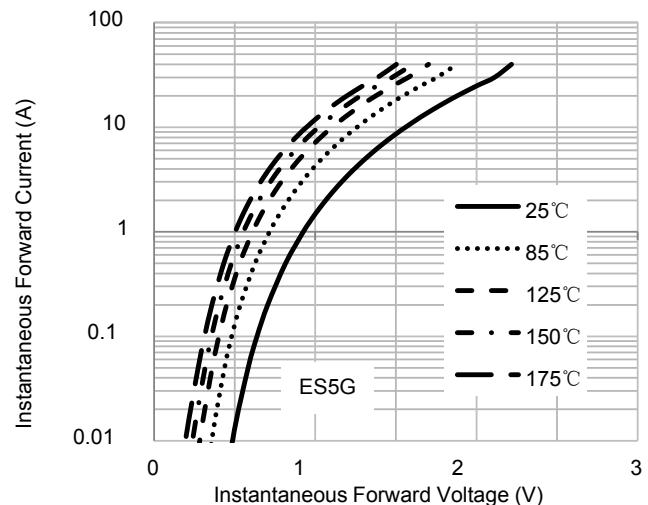


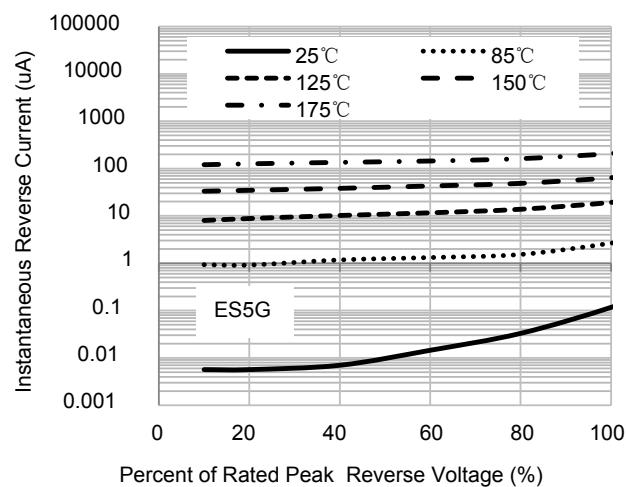
Figure 6. Typical Instantaneous Forward Characteristics



**Figure 7. Typical Reverse Characteristics**

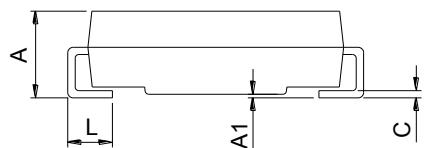
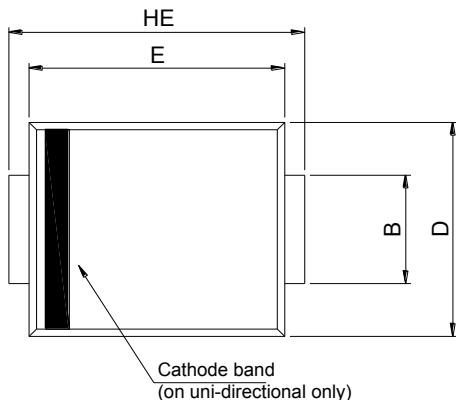


**Figure 8. Typical Instantaneous Forward Characteristics**



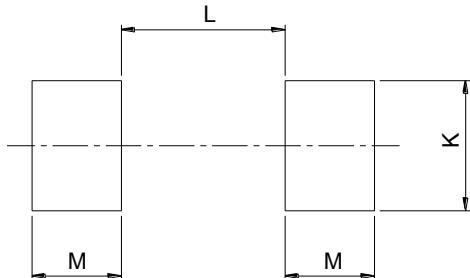
**Figure 9. Typical Reverse Characteristics**

## Package Outline Dimensions DO-214AB (SMC)



DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.00	2.62	0.079	0.103
A1	0.00	0.20	0.000	0.008
B	2.90	3.20	0.114	0.126
C	0.15	0.31	0.006	0.012
D	5.58	6.22	0.220	0.245
E	6.60	7.15	0.260	0.281
HE	7.75	8.15	0.305	0.321
L	0.76	1.60	0.030	0.063

## Recommended Pad Layout



DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.
J	-	4.60	-	0.181
K	3.20	-	0.126	-
M	2.00	-	0.079	-